#### SILICON (Si) POWER MOSFET A CEP540L



CET MOS

# CEP540L

## 100V ▲ 40mΩ ▲ 36A ▲ Si MOSFET

SILICON Si MOSFET ▲ THT type N-channel enhancement mode UL94V-0 rated flame retardant epoxy TO220-3L package Super high dense cell density for extremely low R<sub>DS(ON)</sub> High power and current handling capability

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#### **MAXIMUM RATINGS**

Parameter (T <sub>c</sub> = 25°C, unless otherwise noted)		Characteristics
Drain-Source Voltage	V <sub>DS</sub>	100V
Gate-Source Voltage	V <sub>GS</sub>	±20V
Continuous Drain Current at T <sub>c</sub> = 25°C	I <sub>D</sub>	36A
Pulsed Drain Current Note 1	I <sub>DM</sub>	120A
Maximum Power Dissipation at T <sub>c</sub> = 25°C	PD	140W
Power Dissipation Derating above 25°C	ΔP <sub>D</sub>	0.91W/°C
Single Pulsed Avalanche Energy Note 4	E <sub>AS</sub>	310mJ
Single Pulsed Avalanche Current Note 4	I <sub>AS</sub>	18A
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55°C to +175°C

## **THERMAL CHARACTERISTICS**

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R <sub>TH_JC</sub>	1.1°C/W
Thermal Resistance, Junction-to-Ambient Note 2	R <sub>th_ja</sub>	62.5°C/W

## **APPLICATIONS**

Battery Management Systems	E-Bike	Industrial Control	Power Inverter	UPS
+ 4 -	50			

#### **PIN DESCRIPTION**

Circuit Diagram	Outline - Front View	Pin No.	Description
G (1)		1	Gate
G (1)		2	Drain
S (3)		3	Source

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## **ELECTRICAL CHARACTERISTICS** A T<sub>c</sub> = 25°C, unless otherwise noted

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V$ , $I_D = 250\mu A$	BV <sub>DSS</sub>	100			V
Zero Gate Voltage Drain Current	$V_{DS}$ = 100V, $V_{GS}$ = 0V	I <sub>DSS</sub>			25	μA
Gate Body Leakage Current, Forward	$V_{GS} = 20V$ , $V_{DS} = 0V$	I <sub>GSSF</sub>			100	nA
Gate Body Leakage Current, Reverse	$V_{GS}$ = -20V, $V_{DS}$ = 0V	I <sub>GSSR</sub>			-100	nA
On Characteristics Note 3						
Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250 \mu A$	V <sub>GS(th)</sub>	1		3	V
Static Drain-Source On-Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 18A	R <sub>DS(ON)</sub>		40	50	mΩ
Static Drain-Source On-Resistance	$V_{GS} = 5V, I_{D} = 15A$	R <sub>DS(ON)</sub>		43	53	mΩ
Forward Transconductance	V <sub>DS</sub> = 25V, I <sub>D</sub> = 18A	g <sub>FS</sub>		14		S
Dynamic Characteristics Note 3						
Input Capacitance	$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz	CISS		1295		рF
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$	Coss		199		pF
Reverse Transfer Capacitance	$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz	C <sub>RSS</sub>		40		рF
Switching Characteristics Note 3						
Turn-On Delay Time	$V_{\text{DD}}$ = 50V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 18A, $R_{\text{G(ext)}}$ = 5.1 $\Omega$	t <sub>D(ON)</sub>		13	26	ns
Turn-On Rise Time	$V_{\text{DD}}$ = 50V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 18A, $R_{\text{G(ext)}}$ = 5.1 $\Omega$	t <sub>R</sub>		3.1	7	ns
Turn-Off Delay Time	$V_{\text{DD}}$ = 50V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 18A, $R_{\text{G(ext)}}$ = 5.1 $\Omega$	t <sub>D(OFF)</sub>		55	110	ns
Turn-Off Fall Time	$V_{\text{DD}}$ = 50V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 18A, $R_{\text{G(ext)}}$ = 5.1 $\Omega$	t <sub>F</sub>		5	10	ns
Total Gate Charge	$V_{DD}$ = 80V, $V_{GS}$ = 10V, $I_{D}$ = 18A	Q <sub>G</sub>		40	80	nC
Gate Source Charge	$V_{DD}$ = 80V, $V_{GS}$ = 10V, $I_D$ = 18A	Q <sub>GS</sub>		3.7		nC
Gate Drain Charge	$V_{DD}$ = 80V, $V_{GS}$ = 10V, $I_{D}$ = 18A	$\mathbf{Q}_{GD}$		10		nC
Drain-Source Diode Characteristics a	nd Maximum Ratings					
Drain-Source Diode		ls			36	А
Forward Current Drain-Source Diode Forward Voltage Note 2	V <sub>GS</sub> = 0V, I <sub>S</sub> = 18A	V <sub>SD</sub>			1.3	V

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: L = 1mH,  $I_{AS} = 15A$ ,  $V_{DD} = 50V$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^{\circ}C$

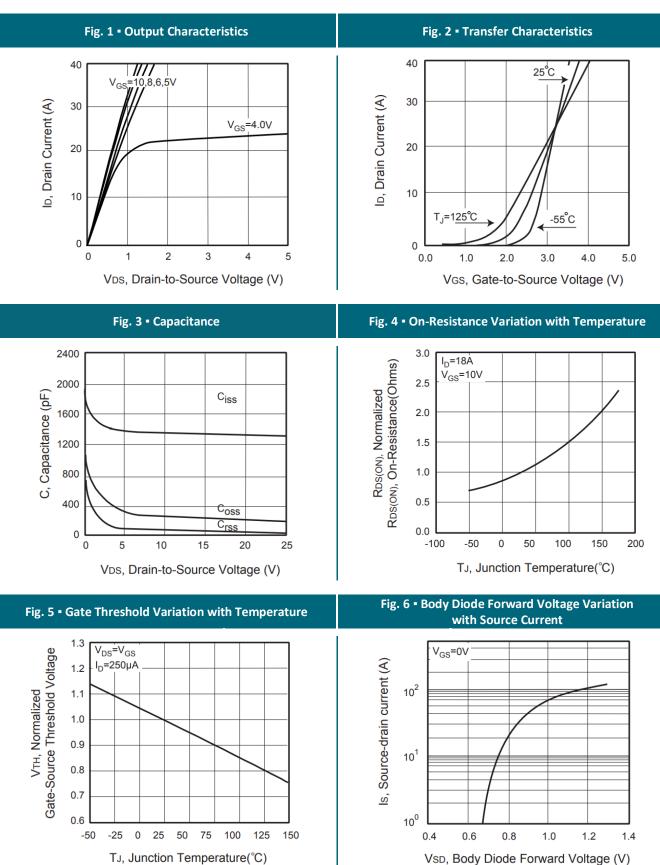


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## **REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE**

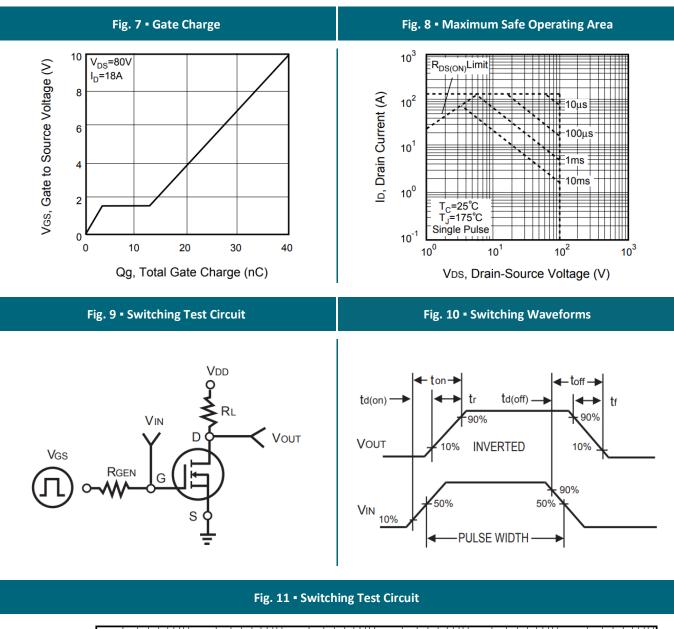


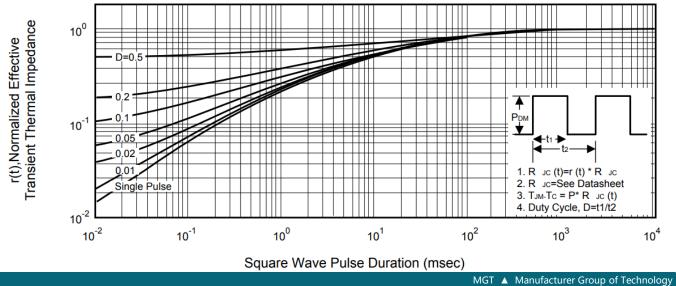
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## **REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE**

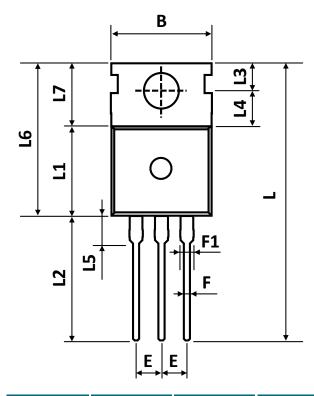


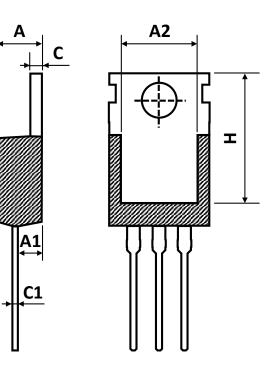


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## **PACKAGE OUTLINE**





Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	4.43	4.53	4.63
A1	2.30	2.40	2.50
A2	7.70	7.90	8.10
В	9.80	10.00	10.20
С	1.25	1.30	1.40
C1	0.45	0.50	0.60
D	3.45	3.60	3.70
E	2.45	2.54	2.60
F	0.70	0.80	0.95
F1	1.15	1.33	1.50
L	26.80	28.80	30.80
L1	9.20	9.30	9.40
L2	12.80	13.10	13.40
L3	2.70	2.80	2.90
L4	3.50	3.70	3.80
L5	2.60	2.90	3.20
L6	15.40	15.80	16.20
L7	6.20	6.50	6.80
н	12.95	13.25	13.55

## **ORDERING INFORMATION**

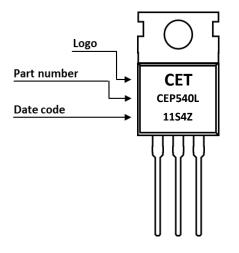
Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
CEP540L	TO-220-3L	Tube	50pcs	1,000pcs	4,000pcs
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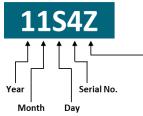
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## **PART MARKING**



## DATE CODE

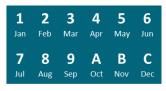
Example: 11S4Z



Product Type Z: Pb-free G: Green Product

	Coding list for "Day"								
<b>1</b>	<b>2</b>	<b>3</b>	<b>4</b>	<b>5</b>	<b>6</b>	<b>7</b>	<b>8</b>	<b>9</b>	<b>A</b>
01	02	03	04	05	06	07	08	09	10
<b>B</b>	<b>C</b>	<b>D</b>	<b>E</b>	<b>F</b>	<b>G</b>	<b>H</b>	<b> </b>	<b>J</b>	<b>K</b>
11	12	13	14	15	16	17	18	19	20
<b>L</b>	<b>M</b>	<b>N</b>	<b>0</b>	<b>P</b>	<b>Q</b>	<b>R</b>	<b>S</b>	<b>T</b>	<b>U</b>
21	22	23	24	25	26	27	28	29	30
<b>V</b> 31									

Coding list for "Month"



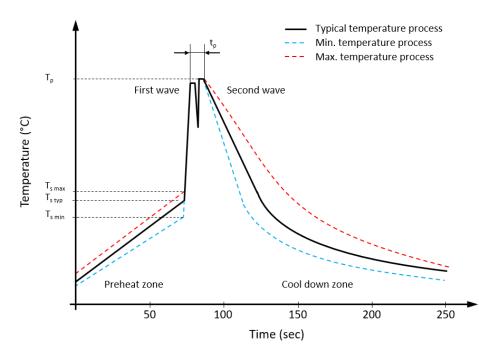
Coding list for "Year"







## **RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE**



#### Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value 🛦 Sn-Pb Assembly	Value 🔺 Pb-free Assembly
Preheat temperature min.	$T_{s min}$	100 °C	100 °C
Preheat temperature typical	T <sub>s typ</sub>	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time $t_s$ from $T_{s min}$ to $T_{s max}$	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t <sub>p</sub>	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes



#### **REVISION TABLE**

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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